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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of:

MARK B. FUSELIER
DERICK J. WRISTERS
ANDY C. WEI

Serial No.: 10/821,230

Filed: April 8, 2004

For: SEMICONDUCTOR DEVICE FORMED
OVER A MULTIPLE THICKNESS
BURIED OXIDE LAYER, AND
METHODS OF MAKING SAME

Examiner: Donghee Kang

Group Art Unit: 2811


Att'y Docket: 2000.092182/TT5101D

Customer No.: 23720

RESPONSE TO OFFICE ACTION DATED JANUARY 4, 2005

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

CERTIFICATE OF MAILING 37 C.F.R. 1.8	
I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date below:	
March 30, 2005 Date	 Signature

This paper is submitted in response to the Office Action dated January 4, 2005, for which the three-month date for response is April 4, 2005.

A fee in the amount of \$3,450.00 is believed to be due in connection with the present paper. **The Director is authorized to deduct such fee, and any other fees required under 37 C.F.R. §§ 1.16 to 1.21, from Advanced Micro Devices, Inc. Deposit Account No. 01-0365/TT5077D.** In the event the monies in that account are insufficient, the Director is authorized to withdraw funds from Williams, Morgan & Amerson, P.C. Deposit Account No. 50-0786/2000.092182.

Reconsideration of the application in view of the following amendments and remarks is respectfully requested.

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02 FC:1201 800.00 DA